



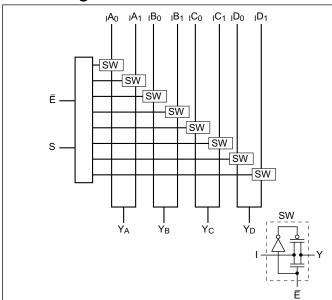
3.3V, Quad 2:1 Mux/DeMux NanoSwitch™

PI3B3257

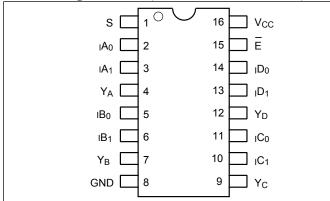
Features

- → Near-Zero propagation delay
- \rightarrow 5 Ω switches connect inputs to outputs
- → Fast Switching Speed: 4.8ns max.
- → Ultra-Low Quiescent Power: 0.1µA typical - Ideally suited for notebook applications
- \rightarrow Pin compatible with 74 series 257 logic devices
- → Packaging (Pb-free & Green avaliable):
 - 16-pin, QSOP (Q)
 - 16-pin, SOIC (W)
 - 16-pin, TSSOP (L)
 - 16-pin, UQFN (ZHD)

Block Diagram



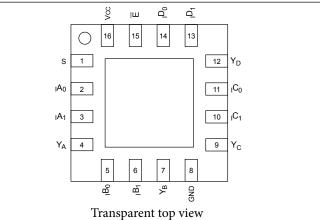
Pin Configuration (QSOP, SOIC, TSSOP)



Description

The PI3B3257 is a 3.3 Volt, Quad 2:1 multiplexer/demultiplexer with three-state outputs that is pinout and function compatible with the PI74FCT257T, 74F257, and 74ALS/AS/LS257. Inputs can be connected to outputs with low On-Resistance (5 Ω) with no additional ground bounce noise or propagation delay.

Pin Configuration (UQFN)



Truth Table⁽¹⁾

Ē	S	YA	YB	YC	YD	Function
Н	Х	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Disable
L	L	IA0	IB0	$_{\rm I}C_0$	ID0	S = 0
L	Н	$_{I}A_{1}$	$_{I}B_{1}$	$_{I}C_{1}$	$_{I}D_{1}$	S = 1
Notes						

Note:

1. H = High Voltage Level

L = Low Voltage Level

Pin Description

Pin Name	Description
IAN-IDN	Data Inputs
S	Select Inputs
Ē	Enable
YA-YD	Data Outputs
GND	Ground ⁽¹⁾
V _{CC}	Power
NC	No Connect

Note 1: UQFN16 package die supply ground is connected to both GND pin and exposed center pad. GND pin must be connected to supply ground for proper device operation. For enhanced thermal, electrical, and board level performance, the exposed pad needs to be soldered to the board using a corresponding thermal pad on the board and for proper heat conduction through the board, thermal vias need to be incorporated in the PCB in the thermal pad region.





Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature Ambient Temperature with Power Applied Supply Voltage to Ground Potential DC Input Voltage DC Output Current	65°C to +150°C
Ambient Temperature with Power Applied	-40°C to +85°C
Supply Voltage to Ground Potential	-0.5V to +4.6V
DC Input Voltage	-0.5V to +4.6V
DC Output Current	120mA
Power Dissipation	

Note: Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of he device at these or any other conditions above those ndicated in the operational sections of this specification s not mplied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

DC Electrical Characteristics (Over the Operating Range, $T_A = -40^{\circ}C$ to $+85^{\circ}C$, $V_{CC} = 3.3V \pm 10\%$)

Parameters	Description	Test Conditions ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Units
V _{IH}	Input HIGH Voltage	Guaranteed Logic HIGH Level	2			v
V _{IL}	Input LOW Voltage	Guaranteed Logic LOW Level	-0.5		0.8	v
I _{IH}	Input HIGH Current	$V_{CC} = Max., V_{IN} = V_{CC}$			±1	
I _{IL}	Input LOW Current	$V_{CC} = Max., V_{IN} = GND$			±1	μA
I _{OZH}	High Impedance Output Current	$0 \leq In, Yn \leq V_{CC}$			±1	
V _{IK}	Clamp Diode Voltage	$V_{CC} = Min., I_{IN} = -18mA$			-1.2	V
R _{ON}	Switch On-Resistance ⁽³⁾	$V_{CC} = Min., V_{IN} = 0.0V,$ Ion = 48mA or 64mA		5	8	Ω
		$V_{CC} = Min., V_{IN} = 2.4V, I_{ON} = 15mA$		8	17	

Notes:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.

Typical values are at $V_{CC} = 3.3V$, $T_A = 25^{\circ}C$ ambient and maximum loading. 2.

Measured by the voltage drop between I and Y pin at indicated current through the switch. On-Resistance is determined by the lower of the voltages on the two 3. (I,Y) pins.

Capacitance ($T_A = 25^{\circ}C$, f = 1 MHz)

Parameters ⁽¹⁾	Description	Test Conditions	Тур.	Units
C _{IN}	Input Capacitance		3.0	
COFFYN	Y _N Capacitance, Switch OFF	$\mathbf{V}_{-z} = 0\mathbf{V}_{-z}$	17.0	ъE
COFFIN	I _N Capacitance, Switch OFF	$V_{IN} = 0V$	8.5	pF
C _{ON}	I _N /Y _N Capacitance, Switch ON		25	

Notes:

This parameter is determined by device characterization but is not production tested. 1

Power Supply Characteristics

Parameters	Description	Test Conditions ⁽¹⁾		Min.	Typ. ⁽²⁾	Max.	Units
I _{CC}	Quiescent Power Supply Current	$V_{CC} = Max.$	$V_{IN} = GND \text{ or } V_{CC}$		0.1	3.0	
ΔI _{CC}	Supply Current per Input @ TTL HIGH ^(3, 4)	$V_{CC} = Max.$	$V_{IN} = 3.0$			750	μΑ

Notes:

For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device. 1.

2. Typical values are at $V_{CC} = 3.3V$, +25°C ambient.

3. Per TTL driven input (control inputs only); I and Y pins do not contribute to I_{CC}.

This current applies to the control inputs only and represent the current required to switch internal capacitance at the specified frequency. The I and Y inputs 4. generate no significant AC or DC currents as they transition. This parameter is not tested, but is guaranteed by design.





Switching Characteristics Over Operating Range

		Conditions	PI3B3257		Units
Parameters	Description		Com.		
			Min.	Max.	
t _{IY}	Propagation Delay In to $Yn^{(1,2)}$			0.25	
t _{SY}	Bus Select Time, Sn to Yn		1	4.5	
t _{PZH} t _{PZL}	Bus Enable Time, E to Yn	$C_{L} = 50 \text{pF}$ $R_{L} = 500 \Omega$	1	4.5	ns
t _{PHZ} t _{PLZ}	Bus Disable Time, E to Yn		1	4.8	

Notes:

This parameter is guaranteed but not tested on Propagation Delays. 1.

The bus switch contributes no propagational delay other than the RC delay of the On-Resistance of the switch and the load capacitance. The switch's time constant 2 alone is of the order of 0.25ns for 50pF load. Since this time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagational delay to the system. Propagational delay of the bus switch when used in a system is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

Applications Information

Logic Inputs

The logic control inputs can be driven up to +3.6V regardless of the supply voltage. For example, given a + 3.3V supply, IN may be driven low to 0V and high to 3.6V. Driving IN Rail-to-Rail* minimizes power consumption.

Power-Supply Sequencing and Hot-Plug Information

Proper power-supply sequencing is recommended for all CMOS devices. Always apply V_{CC} and GND before applying signals to input/ output or control pins.

Rail-to-Rail is a registeredtrademark of Nippon Motorola, Ltd.

Part Marking



Y: Year W: Workweek 1st X: Assembly Site Code 2nd X: Fab Site Code





Y: Year W: Workweek 1st X: Assembly Site Code 2nd X: Fab Site Code

W Package



YY: Date Code (Year) WW: Date Code (Workweek) 1st X: Assembly Site Code 2nd X: Fab Site Code

L Package

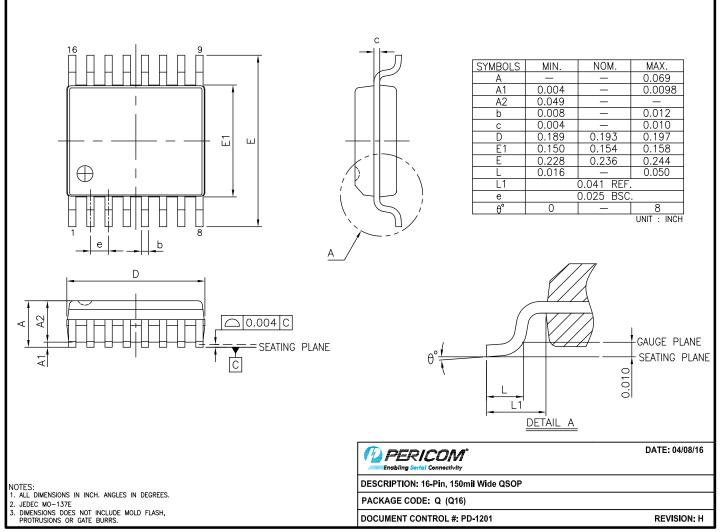


YY: Year WW: Workweek 1st X: Assembly Site Code 2nd X: Fab Site Code





Packaging Mechanical: 16-QSOP(Q)

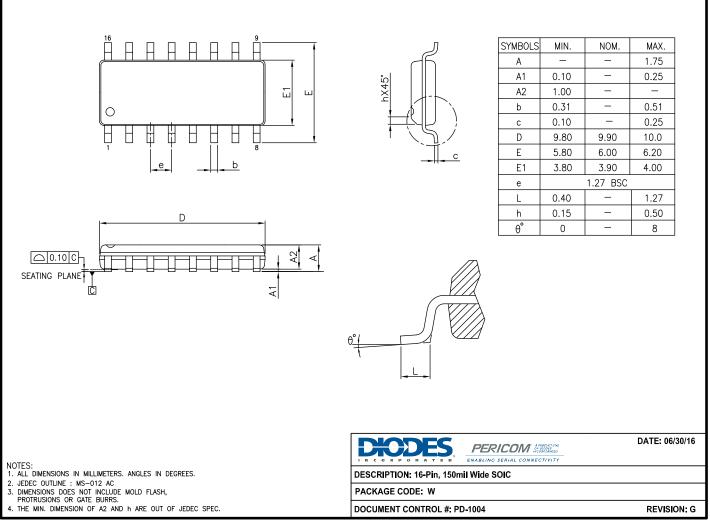


16-0056





Packaging Mechanical: 16-SOIC (W)

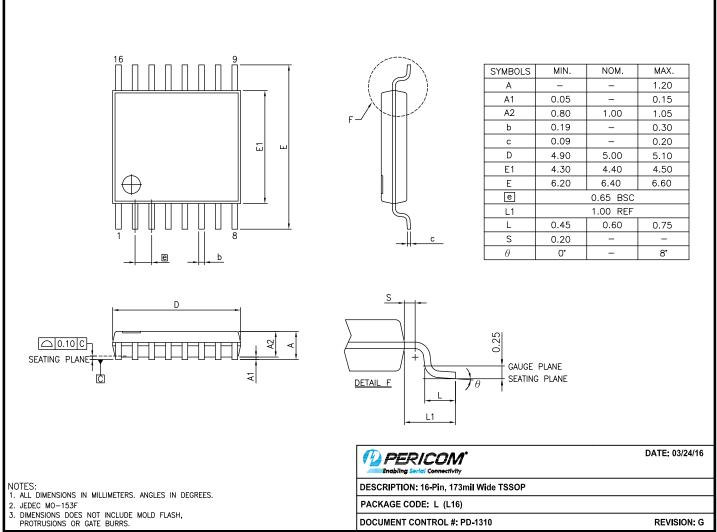


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Packaging Mechanical: 16-TSSOP(L)

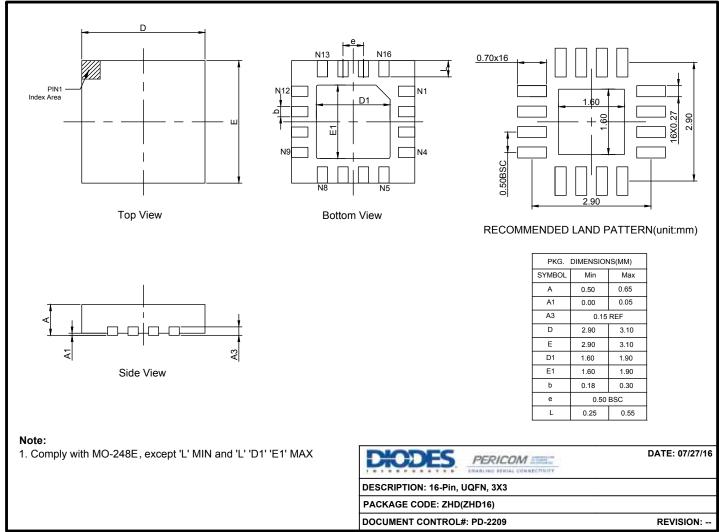


16-0061





Packaging Mechanical: 16-UQFN (ZHD)



16-0092

For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

Ordering Code	Packaging Code	Package Description
PI3B3257QEX	Q	16-pin, 150 mil wide (QSOP)
PI3B3257WEX	W	16-pin, 150-mil wide (SOIC)
PI3B3257LEX	L	16-pin, 173 mil wide (TSSOP)
PI3B3257ZHDEX	ZHD	16-pin, 3x3 (UQFN)

Notes:

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. Thermal characteristics can be found on the company web site at www.diodes.com/design/support/packaging/

3. E = Pb-free and Green

4. X suffix = Tape/Reel